

Power Resistor for Mounting onto a Heatsink Thick Film Technology



FEATURES

- 1 % tolerance available
- High power rating = 200 W
- Wide ohmic value range = 0.046 Ω to 1 MΩ
- Non inductive
- Easy mounting
- Low thermal radiation of the case
- Standard Isotop case (SOT 227 B)

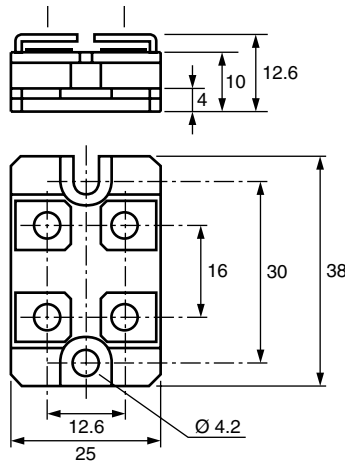


This series of thick film power resistors include modules which can incorporate up to 2 different resistor values in the same SOT 227B package. Two types of terminations are available along with a 4 terminal device for measurement applications in the case of the single resistor version. This product range benefits from Vishay Sfernice's experience in thick film power resistor technology i.e. high power: volume ratio, low tolerance or individual resistors and excellent overload capabilities (due to the trimming technique).

DIMENSIONS in millimeters

RTOP

V Connections



• Tolerances unless otherwise specified: ± 0.3 mm

MECHANICAL SPECIFICATIONS

Mechanical Protection	Insulated case
Substrate	Alumina on insulated base
Resistive Element	Cermet
End Connections	V connections: screw M4 x 6
Tightening Torque Connections	1 Nm
Tightening Torque Heatsink	2 Nm
Weight	30 g max.

ENVIRONMENTAL SPECIFICATIONS

Temperature Range	- 55 °C to + 125 °C
Climatic Category	55/125/56

ELECTRICAL SPECIFICATIONS

Resistance Range	0.046 to 1 MΩ
Standard Tolerance	± 1 % to ± 10 %
Power Rating	50 W to 200 W at + 25 °C
Temperature Coefficient (- 55 °C to + 125 °C)	Standard ± 300 ppm/°C (R < 1) ± 150 ppm/°C (R > 1)
Insulation Resistance	> 10 ⁶ MΩ

PERFORMANCE		
TESTS	CONDITIONS	REQUIREMENTS
Momentary Overload	IEC 60115-1 2.5 Pn/5 s $U_S < 2 U_L$	$< \pm (0.25 \% + 0.05 \Omega)$
Rapid Temperature Change	IEC 60115-1 5 cycles - 55 °C + 125 °C	$< \pm (0.25 \% + 0.05 \Omega)$
Load Life	IEC 60115-1 Pn at 25 °C 1000 h	$< \pm (0.5 \% + 0.05 \Omega)$
Humidity (Steady State)	IEC 60115-1/IEC 60068-2-3 Test Ca 56 days 95 % R.H./40 °C	$< \pm (0.5 \% + 0.05 \Omega)$

SPECIAL FEATURES				
MODEL	RTOP 200	RTOP 100	DRTOP 100	DRTOP 50
Power Rating at + 25 °C Chassis Mounted Resistors Unmounted Resistors	200 W 5 W	100 W 5 W	100 W 3.5 W	50 W 3.5 W
Thermal Resistance (Per Resistor)	0.5 °C/W	1 °C/W	0.5 °C/W	1 °C/W
Limiting Voltage U_L	1500 V	1500 V	500 V	500 V
Dielectric Strength ⁽¹⁾ Connections/Chassis	2500 V, 1 min 10 mA max.	2500 V, 1 min 10 mA max.	2500 V, 1 min 10 mA max.	2500 V, 1 min 10 mA max.
Dielectric Strength ⁽¹⁾ Connections/Resistors	-	-	2500 V, 1 min 10 mA max.	2500 V, 1 min 10 mA max.
Ohmic Value Range	0.046 Ω to 1 M Ω		0.092 Ω to 1 M Ω	
Tolerance	$\pm 1 \%$ to $\pm 10 \%$		$\pm 1 \%$ to $\pm 10 \%$	
Electrical Diagrams	<p style="text-align: center;">Shunt Version</p>			

Note
⁽¹⁾ MIL STD 202 Method 301

CHOICE OF THE HEATSINK

The user must choose the heatsink according to the working conditions of the component (power, room temperature). Maximum working temperature must not exceed 125 °C. The dissipated power is simply calculated by the following ratio:

$$P = \frac{\Delta T}{[R_{TH(j-c)} + R_{TH(c-a)}]} \quad (1)$$

- P: Expressed in W
- ΔT : Difference between maximum working temperature and room temperature.
- $R_{TH(j-c)}$: Thermal resistance value measured between resistive layer and outer side of the resistor. It is the thermal resistance of the component (see Table Special Features).
- $R_{TH(c-a)}$: Thermal resistance value measured between outer side of the resistor and room temperature. It is the thermal resistance of the heatsink depending on the heatsink itself (type, shape) and the quality of the fastening device.

Example:

$R_{TH(c-a)}$: For RTOP 200 power rating 130 W at ambient temperature + 30 °C.

Thermal resistance (see table 1) $R_{TH(j-c)}$: 0.5 °C/W

$$\Delta T \leq 125 \text{ °C} - 30 \text{ °C} = \leq 95 \text{ °C}$$

$$R_{TH(j-c)} + R_{TH(c-a)} = \frac{\Delta T}{P} = \frac{95}{130} = 0.73 \text{ °C/W}$$

$$R_{TH(j-c)} \leq 0.5 \text{ °C/W}$$

$$R_{TH(c-a)} \leq 0.73 \text{ °C/W} - 0.5 \text{ °C/W} \leq 0.23 \text{ °C/W}$$

OVERLOADS

The applied power is 2.5 x rated power for 5 s with a max. voltage of 2 x nominal voltage.

Accidental overload: The values indicated in the graph below are applicable to resistors in air or mounted onto a heatsink.

In case of multi-resistor devices, (DRTOP, TROP and QROP) the results apply to each resistor value in the device.

RECOMMENDATIONS FOR MOUNTING ONTO A HEATSINK

Surfaces in contact must be carefully cleaned.

The heatsink must have an acceptable flatness: from 0.05 mm to 0.1 mm/100 mm.

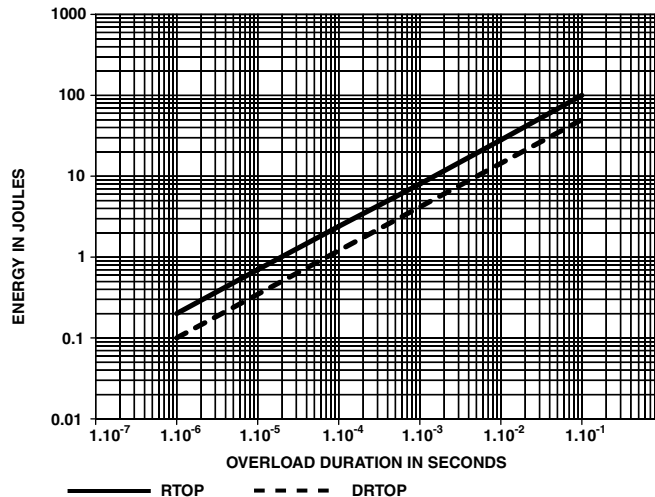
Roughness of the heater must be around 6.3 μm.

In order to improve thermal conductivity, surfaces in contact (alumina, heatsink) are laid on with a silicone grease (type SI 340 from Rhône-Poulenc or Dow 340 from Dow Corning).

Tightening torque on heater: 2 Nm

For the electrical connections, it is recommended to use M4 x 6 screws and if necessary a washer of 1mm thickness. The recommended screw tightening torque is 1 Nm.

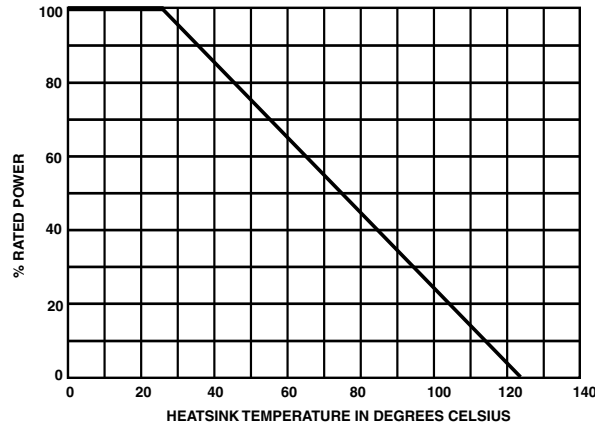
ENERGY CURVE





POWER RATING CHART

The temperature of the heater should be maintained in the limit specified. To improve the thermal conductivity, surfaces in contact should be laid on with a silicon grease and the torque applied on the screw for tightening should be around 2 Nm.



MARKING

Series, style, ohmic value (in), tolerance (in %), manufacturing date, VISHAY trade mark.

PACKAGING

Box of 10 units

ORDERING INFORMATION									
RTOP	200	5U	± 1 %	± %	V				
DRTOP	50	150U	5 %	15U	5 %	V	XXX	BO10	e
MODEL	STYLE	OHMIC VALUE	ABSOLUTE TOLERANCE PER RESISTOR		CONNECTIONS	CUSTOM DESIGN	PACKAGING	LEAD (Pb)-FREE	
RTOP	100		Optional	To be precise	V: Screw	Optional			
DRTOP	50		± 1 %	for each resistor	VS: RTOP Shunt				
			± 2 %						
			± 5 %						
			± 10 %						

GLOBAL PART NUMBER INFORMATION										
<div style="display: flex; justify-content: space-around; font-weight: bold; font-size: 1.2em;"> RTOP100V5R00KB </div>										
GLOBAL MODEL	SIZE	LEADS	OHMIC VALUE				TOL.	PACKAGING	SPECIAL	
RTOP	100 200	V = Screw VS = RTOP Shunt	The first three digits are significant figures and the last digit specifies the number of zeros to follow. R designates decimal point. 48R7 = 48.7 Ω 4871 = 4870 Ω 1002 = 10 000 Ω R010 = 0.01 Ω R680 = 0.68 Ω 2700 = 2.7 kΩ				F = 1 % G = 2 % J = 5 % K = 10 %	B = Box 10 pieces	As applicable Ex = UA1	



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